



1

Evaluation of Mass Produced PWO Crystals

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BTCP: 20 from 1st batch (100) for CMS endcaps SIC: 20 from production batch for PrimEx





Experiment



- All crystals went through (1) thermal annealing at 200°C, (2) irradiations by γ–ray at 15, 400 and 9k rad/h until equilibrium and (3) recovery.
- Properties measured: Transmittance, emission and excitation spectrum, light output, decay kinetics and light response uniformity, as well as their degradation, radiation induced color center and emission weighted radiation induced absorption coefficients.
- Light output degradation was only measured at 15 rad/h because of limited light output: less than 8 p.e./MeV for BTCP samples.



Thermal Annealing

- Rigorous temperature control both in amplitude and slope:
 - From RT to 200°C: 200 minutes;
 - Maintain at 200°C: 240 minutes;
 - From 200°C to 25°C: 400 minutes.
- Crystals are kept in dark at RT (18°C) after annealing. The minimum time between annealing and the 1st measurement is 48 hours.











Bridgman: grown along the *c axis*

a axis: better longitudinal T., but non-isotropic transverse T. Both approaching theoretical limit

Czochralski: grown along the *a axis*



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SIC samples have higher light output Both are fast: 84 and 96% of light in 50 and 100 ns







Comparison of L.T. and Light Yield

BTCP:higher I. transmittance, partly due to birefringence

SIC: higher light yield, the reason is unknown





Caltech y-ray Irradiation Facilities



Open 50 curie Co-60: 15, 100 and 400 rad/h

Closed 2,000 curie Cs-137: 9k rad/h at center, up to 36k rad/h











No variation in either excitation or emission spectrum No damage in scintillation mechanism





No Variation in Light Response Uniformity



The response (y) along the axis was fit to a linear function









Light Output Degradation

5-15% and 15-30% light output loss under 15 and 500 rad/h Damage is dose rate dependent







Radiation induced absorption caused by CC formation









SIC samples seem more radiation hard





Comparison of Transmittance Loss



Some BTCP samples are very rad hard at high doses









Nucl. Instr. And Meth. A332 (1993) 442

RIAC or radiation induced color center density can be calculated precisely by using longitudinal transmittance (0.2%)



$$LAL = \frac{\ell}{\ln\{[T(1-T_s)^2]/[\sqrt{4T_s^4 + T^2(1-T_s^2)^2} - 2T_s^2]\}}$$

where *T* is transmittance measured along crystal length ℓ and *T_s*
is the theoritical transmittance without internal absorption:
$$T_s = (1-R)^2 + R^2(1-R)^2 + \dots = (1-R)/(1+R),$$
 with

s



Emission Weighted RIAC



 $EWRIAC = \frac{\int Riac(\lambda) Em(\lambda) d\lambda}{\int Em(\lambda) d\lambda}$

a good measure of rad. damage



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EWRIAC (1/m) and Normalized r.m.s



Vendor	15 rad/h	400 rad/h	9.000 rad/h
BTCP	0.16 (45%)	0.69 (37%)	1.43 (50%)
SIC	0.10 (33%)	0.51 (32%)	1.16 (48%)









No correlation







EWRIAC versus Initial L.T. @ 440 nm

No correlation





Recovery Speed and Time Constant



Recovery at 18°C in 160 days can be described by two time constants: few tens hours and few thousands hours





Summary



- Investigation on 20 crystals each from two vendors shows that SIC samples are more consistent (Bridgman).
- Samples from both vendors have very good transmittance and fast light output. It is not clear why SIC samples produce more (58%) light.
- No correlations between radiation hardness and initial longitudinal transmittance was observed.
- Current mass-produced PWO crystals are radiation hard enough for environment of up to a few hundreds rad/h by selection. R&D is needed if thousands rad/h is expected (SLHC).
- Some samples (from BTCP) are very radiation hard (Type I), which should be further studied.





PWO Crystals Grown along *c* axis Isotropic transverse transmittance uniformity along crystal length







Not isotropic transverse transmittance Not uniform along crystal length









Type III sample: preexisting intrinsic color center at 420 nm after 200 degree annealing, causing difficulty for monitoring with 440 nm light